



Form PTO 1449 (Modified)		U.S. DEPARTMENT OF COMMERCE PATENT AND TRADEMARK OFFICE		ATTY DOCKET NO. 240193US2		SERIAL NO. 10/617,046	
LIST OF REFERENCES CITED BY APPLICANT				APPLICANT Tamio IKEHASHI, et al.			
				FILING DATE July 11, 2003		GROUP	
U.S. PATENT DOCUMENTS							
EXAMINER INITIAL		DOCUMENT NUMBER	DATE	NAME	CLASS	SUB CLASS	FILING DATE IF APPROPRIATE
TL	AA	6,538,916	03/25/2003	T. OHSAWA			
	AB						
	AC						
	AD						
	AE						
	AF						
	AG						
	AH						
	AI						
	AJ						
	AK						
	AL						
	AM						
	AN						
FOREIGN PATENT DOCUMENTS							
		DOCUMENT NUMBER	DATE	COUNTRY	TRANSLATION YES NO		
TL	AO	2-3165	01/08/90	JAPAN (with English Abstract)			X
	AP						
	AQ						
	AR						
	AS						
	AT						
	AU						
	AV						
OTHER REFERENCES (Including Author, Title, Date, Pertinent Pages, etc.)							
TL	AW	T. OHSAWA, et al., ISSCC 2002 / Session 9 / Dram and Ferroelectric Memories 9. 1, pages 152-153, "MEMORY DESIGN USING ONE-TRANSISTOR GAIN CELL ON SOI", 2002					
	AX						
	AY						
	AZ					<input type="checkbox"/> Additional References sheet(s) attached	
Examiner <i>Moyle</i>					Date Considered <i>7/10/05</i>		
*Examiner: Initial if reference is considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.							



LIST OF RELATED CASES

<u>Docket Number</u>	<u>Serial or Patent Number</u>	<u>Filing or Issue Date</u>	<u>Inventor/ Applicant</u>
TL 240193US2*	10/617,046	07/11/03	IKEHASHI et al.
TL 253054US2S	10/854,403	05/14/04	YAMADA et al.

choyle 3/10/05